

# **4V Drive Nch MOSFET**

## RSJ300N10

#### Structure

Silicon N-channel MOSFET

#### Features

- 1) Low on-resistance.
- 2) Built-in G-S Protection Diode.

### Application

Switching

#### Packaging specifications

	Package	Taping	
Type	Code	TL	
	Basic ordering unit (pieces)	1000	
RSJ300N1	0		

#### ● Absolute maximum ratings (Ta = 25°C)

Parameter		Symbol	Limits	Unit
Drain-source voltage		$V_{DSS}$	100	V
Gate-source voltage		$V_{GSS}$	±20	V
Drain current	Continuous	I <sub>D</sub> *1	±30	Α
	Pulsed	I <sub>DP</sub> *2	±60	Α
Source current (Body Diode)	Continuous	l <sub>S</sub> *1	30	Α
	Pulsed	I <sub>SP</sub> *2	60	Α
Power dissipation		P <sub>D</sub> *3	50	W
Channel temperature		Tch	150	°C
Range of storage temperature		Tstg	-55 to +150	°C

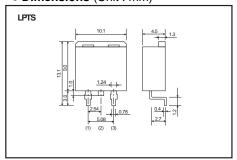
<sup>\*1</sup> Limited only by maximum temperature allowed.

#### • Thermal resistance

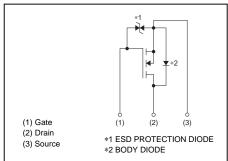
Parameter	Symbol	Limits	Unit
Channel to Case	Rth (ch-c)*	2.5	°C/W

<sup>\*</sup>Mounted on a ceramic board.

## • Dimensions (Unit : mm)



#### • Inner circuit



<sup>\*2</sup> Pw≦10μs, Duty cycle≦1%

<sup>\*3</sup> T<sub>c</sub>=25°C

## ● Electrical characteristics (Ta = 25°C)

Parameter	Symbol	Min.	Тур.	Max.	Unit	Conditions
Gate-source leakage	$I_{GSS}$	-	-	±10	μA	$V_{GS}=\pm20V$ , $V_{DS}=0V$
Drain-source breakdown voltage	$V_{(BR)DSS}$	100	-	-	V	$I_D=1mA, V_{GS}=0V$
Zero gate voltage drain current	I <sub>DSS</sub>	1	-	1	μA	V <sub>DS</sub> =100V, V <sub>GS</sub> =0V
Gate threshold voltage	V <sub>GS (th)</sub>	1.0	-	2.5	V	$V_{DS}$ =10V, $I_{D}$ =1mA
		1	33	52		I <sub>D</sub> =15A, V <sub>GS</sub> =10V
Static drain-source on-state resistance	R <sub>DS (on)</sub> *	-	36	58	mΩ	I <sub>D</sub> =15A, V <sub>GS</sub> =4.5V
Todotarioo		1	38	59		I <sub>D</sub> =15A, V <sub>GS</sub> =4.0V
Forward transfer admittance	I Y <sub>fs</sub> I*	15	-	-	S	I <sub>D</sub> =15A, V <sub>DS</sub> =10V
Input capacitance	C <sub>iss</sub>	-	2200	-	pF	V <sub>DS</sub> =25V
Output capacitance	C <sub>oss</sub>	-	190	-	pF	V <sub>GS</sub> =0V
Reverse transfer capacitance	$C_{rss}$	-	120	-	pF	f=1MHz
Turn-on delay time	t <sub>d(on)</sub> *	1	20	-	ns	I <sub>D</sub> =15A, V <sub>DD</sub> ≒50V
Rise time	t <sub>r</sub> *	-	65	-	ns	V <sub>GS</sub> =10V
Turn-off delay time	t <sub>d(off)</sub> *	-	130	-	ns	$R_L=3.3\Omega$
Fall time	t <sub>f</sub> *	-	180	-	ns	$R_G=10\Omega$
Total gate charge	Q <sub>g</sub> *	-	50	-	nC	I <sub>D</sub> =30A, V <sub>DD</sub> ≒50V
Gate-source charge	Q <sub>gs</sub> *	-	6	-	nC	V <sub>GS</sub> =10V
Gate-drain charge	Q <sub>gd</sub> *	-	15	-	nC	

<sup>\*</sup>Pulsed

## ●Body diode characteristics (Source-Drain) (Ta = 25°C)

Parameter	Symbol	Min.	Тур.	Max.	Unit	Conditions
Forward Voltage	V <sub>SD</sub> *	-	-	1.5	V	$I_s$ =30A, $V_{GS}$ =0V

<sup>\*</sup>Pulsed

#### ●Electrical characteristic curves (Ta=25°C)

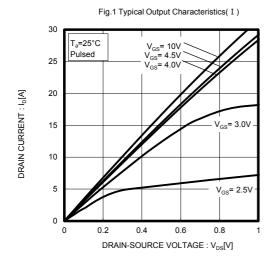


Fig.3 Typical Transfer Characteristics

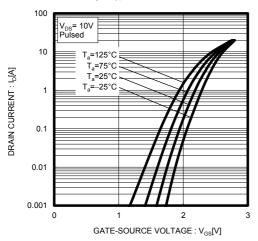


Fig.5 Static Drain-Source On-State Resistance vs. Drain Current( II )

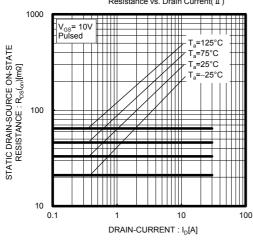


Fig.2 Typical Output Characteristics( II )

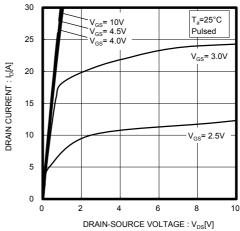


Fig.4 Static Drain-Source On-State Resistance vs. Drain Current( I )

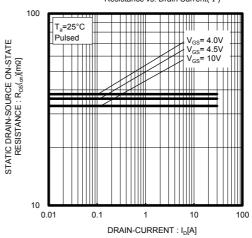
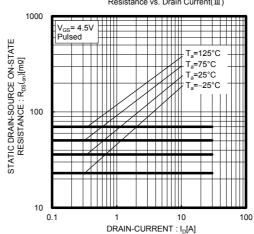
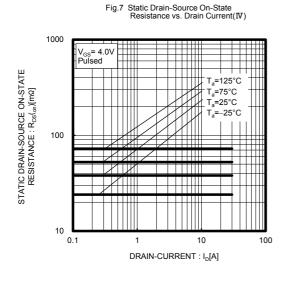
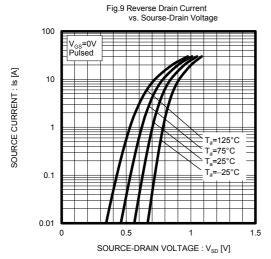
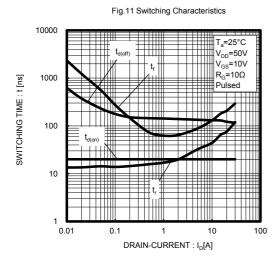


Fig.6 Static Drain-Source On-State Resistance vs. Drain Current(Ⅲ)









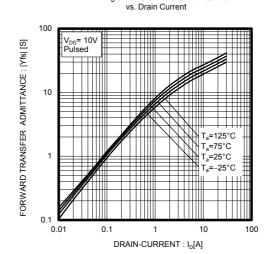
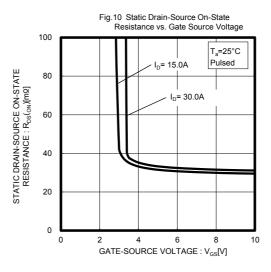
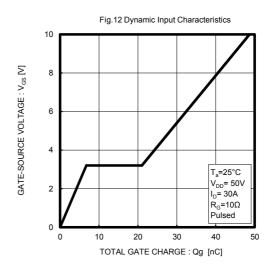


Fig.8 Forward Transfer Admittance





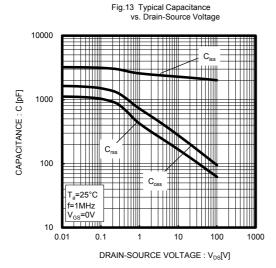
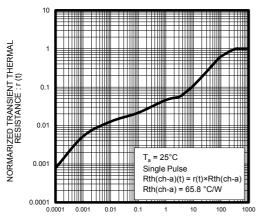
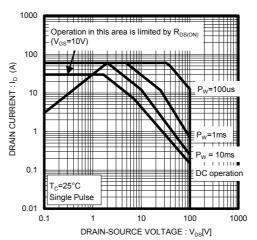


Fig.15 Normalized Transient Thermal Resistance vs. Pulse Width



PULSE WIDTH : Pw(s)

Fig.14 Maximum Safe Operating Aera



#### Measurement circuits

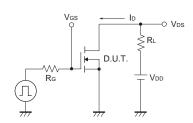


Fig.1-1 Switching Time Measurement Circuit

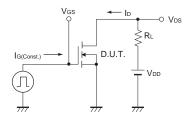


Fig.2-1 Gate Charge Measurement Circuit

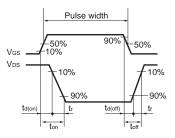


Fig.1-2 Switching Waveforms

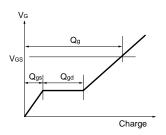


Fig.2-2 Gate Charge Waveform

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